

High voltage fast-switching NPN power transistor

Features

- High voltage capability
- Low spread of dynamic parameters
- Minimum lot-to-lot spread for reliable operation
- Very high switching speed
- Integrated antiparallel collector-emitter diode

Applications

■ Electronic ballast for fluorescent lighting

Description

The device is manufactured using high voltage multi-epitaxial planar technology for high switching speeds and medium voltage capability. It uses a cellular emitter structure with planar edge termination to enhance switching speeds while maintaining the wide RBSOA.

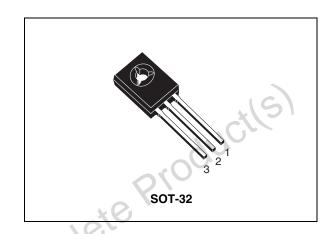


Figure 1. Internal schematic diagram

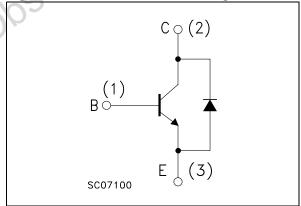


Table 1. Device summary

Order code	Marking	Package	Packaging
ST13003D-K	13003D	SOT-32	Bag

Electrical ratings ST13003D-K

1 Electrical ratings

Table 2. Absolute maximum ratings

	Symbol	Parameter	Value	Unit
	V _{CES}	Collector-emitter voltage (V _{BE} = 0)	700	V
	V _{CEO}	Collector-emitter voltage (I _B = 0)	400	V
	V_{EBO} Emitter-base voltage ($I_C = 0$, $I_B = 0.75$ A, $t_P < 10 \mu s$)		V _{(BR)EBO}	V
	I _C Collector current		1.5	Α
I _{CM}		Collector peak current (t _P < 5 ms)	3	Α
	Ι _Β	Base current	0.75	Α
	I _{BM}	Base peak current (t _P < 5 ms)	1.5	Α
	P _{TOT}	Total dissipation at T _c = 25 °C	40	W
	T _{STG}	Storage temperature	-55 to 150	°C
	T _J	Max. operating junction temperature	150	°C
Obsole	ReP	Storage temperature Max. operating junction temperature		

Electrical characteristics 2

T_{case} = 25 °C unless otherwise specified

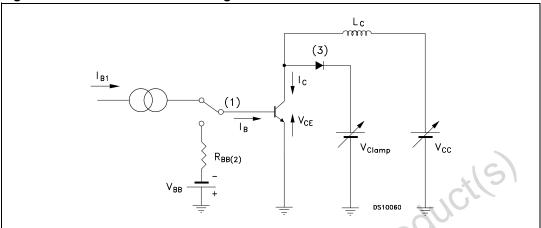
Table 3. **Electrical characteristics**

I_{CES} Collector cut- $(V_{BE} = 0)$ $V_{(BR)EBO}$ Emitter-Base voltage ($I_{C} = 0$ $V_{CEO(sus)}^{(1)}$ Collector-emit sustaining volt $V_{CE(sat)}^{(1)}$ Collector-emit saturation volt	$V_{CE} = 700 \text{ N}$ breakdown $I_{E} = 10 \text{ mA}$ tter tage ($I_{B} = 0$) $I_{C} = 10 \text{ mA}$	/ / T _c = 125 °C	9		1 5 18	mA mA
$V_{(BR)EBO}$ voltage ($I_C = 0$) $V_{CEO(sus)}^{(1)}$ Collector-emit sustaining voltage ($I_C = 0$) $V_{CEO(sus)}^{(1)}$ Collector-emit	tter tage $(I_B = 0)$ $I_C = 10 \text{ mA}$		9		18	٧
VCEO(sus) (1) sustaining vol	tage $(I_B = 0)$ $I_C = 10 \text{ mA}$					
V == (:: \ ' /			400	. (11/5	٧
	Π – Ι Δ	$I_B = 0.1 A$ $I_B = 0.25 A$ $I_B = 0.5 A$	070	90.	0.5 1 3	V V V
V _{BE(sat)} (1) Base-emitter s	saturation $I_C = 0.5 A$ $I_C = 1 A$	$I_B = 0.1 \text{ A}$ $I_B = 0.25 \text{ A}$			1 1.2	V V
h _{FE} DC current ga	$I_C = 0.5 A$ $I_C = 1 A$	V _{CE} = 2 V V _{CE} = 2 V	8 5		20 25	
Resistive load t _r Rise time t _s Storage time t _f Fall time	$V_{CC} = 125 \text{ N}$ $I_{B1} = 0.2 \text{ A}$ $T_p = 25 \mu\text{s}$	$I_{C} = 1 \text{ A}$ $I_{B2} = -0.2 \text{ A}$			1 4 0.7	μs μs μs
Inductive load Storage time	$I_{C} = 1 A$ $V_{BE} = -5 V$ $V_{Clamp} = 30$	$I_{B1} = 0.2 \text{ A}$ L = 50 mH 0 V		0.8		μs
V _F Diode forward	I voltage $I_F = 0.5 A$				1.5	V

Electrical characteristics ST13003D-K

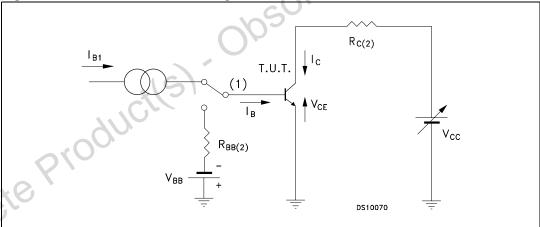
2.1 Test circuits

Figure 2. Inductive load switching test circuit



- 1. Fast electronic switch
- 2. Non-inductive resistor
- 3. Fast recovery rectifier

Figure 3. Resistive load switching test circuit



- 1. Fast electronic switch
- 2. Non-inductive resistor

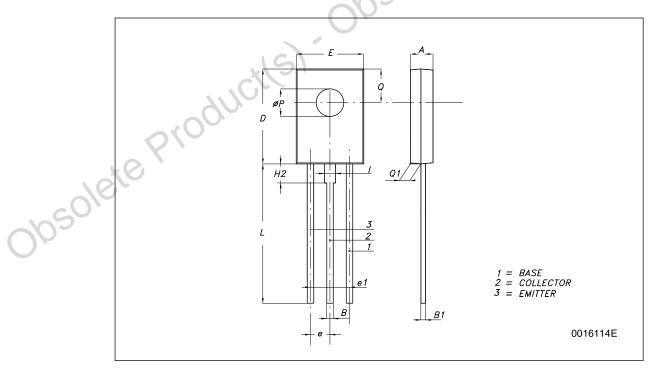
3 Package mechanical data

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Obsolete Product(s). Obsolete Product(s)

SOT-32 (TO-126) MECHANICAL DATA

DIM.		mm.			
DIW.	MIN.	TYP	MAX.		
Α	2.4		2.9		
В	0.64		0.88		
B1	0.39		0.63		
D	10.5		11.05		
E	7.4		7.8		
е	2.04	2.29	2.54		
e1	4.07	4.58	5.08		
L	15.3		16		
Р	2.9		3.2		
Q		3.8	40		
Q1	1		1.52		
H2		2.15			
ı		1.27			



ST13003D-K Revision history

4 Revision history

Table 4. Document revision history

Date	Revision	Changes
15-Nov-2007	1	Initial release.
08-Sep-2009	2	Updated packaging information Table 1 on page 1.

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